# VS-C4ZU3006FP-M3

**Vishay Semiconductors** 



### **Ultrafast Soft Recovery Diode,** 2 x 15 A FRED Pt® Gen 4



PRIMARY CHARACTERISTICS						
I <sub>F(AV)</sub> per leg 15 A						
V <sub>R</sub>	600 V					
V <sub>F</sub> at I <sub>F</sub>	1.08 V					
t <sub>rr</sub> typ.	37 ns					
T <sub>J</sub> max.	175 °C					
Package	TO-3PF					
Circuit configuration	Common cathode					

### **FEATURES**

- Gen 4 FRED Pt technology
- Low I<sub>BBM</sub> and reverse recovery charge
- · Very low forward voltage drop
- · Polyimide passivated chip for high reliability standard
- Fully isolated package (V<sub>INS</sub> = 2500 V<sub>RMS</sub>)
- 175 °C operating junction temperature
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

#### DESCRIPTION

Gen 4 Fred Pt technology, state of the art, ultralow V<sub>F</sub>, soft switching optimized for Discontinuous (Critical) Mode (DCM) and IGBT F/W diode.

The minimized conduction loss, optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Peak repetitive reverse voltage	V <sub>RRM</sub>		600	V			
Average rectified forward current, per leg	I <sub>F(AV)</sub>	T <sub>C</sub> = 120 °C	15	٨			
Non-repetitive peak surge current, per leg	I <sub>FSM</sub>	$T_{C}$ = 25 °C, $t_{p}$ = 8.3 ms half sine wave	180	A			
Operating junction and storage temperature	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +175	°C			

<b>ELECTRICAL SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	SYMBOL TEST CONDITIONS			MAX.	UNITS	
Breakdown voltage, blocking voltage	V <sub>BR</sub> , V <sub>R</sub>	I <sub>R</sub> = 100 μA	600	-	-		
Forward voltage		I <sub>F</sub> = 15 A	-	1.3	1.6	V	
	V <sub>F</sub>	I <sub>F</sub> = 30 A	-	1.46	1.87		
		I <sub>F</sub> = 15 A, T <sub>J</sub> = 150 °C	-	1.08	1.3		
		I <sub>F</sub> = 30 A, T <sub>J</sub> = 150 °C	-	1.32	-		
	I <sub>R</sub>	V <sub>R</sub> = V <sub>R</sub> rated	-	-	15		
Reverse leakage current		$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA	
Junction capacitance	CT	V <sub>R</sub> = 600 V	-	15	-	pF	



COMPLIANT

HALOGEN

FREE



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<b>DYNAMIC RECOVERY CHARACTERISTICS</b> ( $T_J = 25$ °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST	MIN.	TYP.	MAX.	UNITS		
		$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}$	$I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, V_R = 30 \text{ V}$		37	-		
Reverse recovery time, per leg	t <sub>rr</sub>	T <sub>J</sub> = 25 °C	I <sub>F</sub> = 15 A dI <sub>F</sub> /dt = 1000 A/μs V <sub>R</sub> = 400 V	-	73	-	ns	
		T <sub>J</sub> = 125 °C		-	83	-		
Peak recovery current, per leg	I <sub>RRM</sub>	T <sub>J</sub> = 25 °C		-	13	-	•	
		T <sub>J</sub> = 125 °C		-	21	-	A	
Reverse recovery charge, per leg	0	T <sub>J</sub> = 25 °C		-	500	-		
	Q <sub>rr</sub>	T <sub>J</sub> = 125 °C		-	1100	-	nC	

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Thermal resistance, junction to case	R <sub>thJC</sub>		-	-	3	°C/W		
Thermal resistance, case to heatsink	R <sub>thCS</sub>		-	0.5	-			
Weight			-	6.2	-	g		
			-	0.21	-	oz.		
Mounting torque			4.0 (3.5)	-	6.0 (5.3)	kgf · cm (lbf · in)		
Marking device		Case style TO-3PF	C4ZU3006FP					

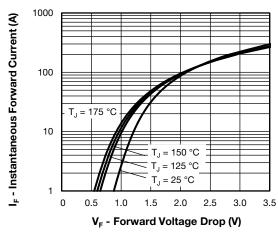


Fig. 1 - Typical Forward Voltage Drop Characteristics

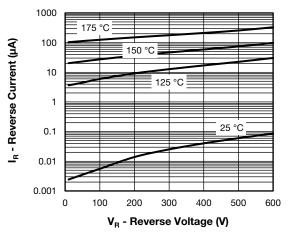


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage



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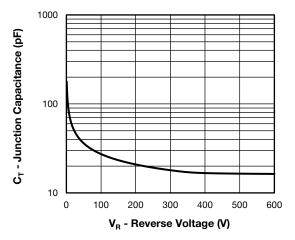


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

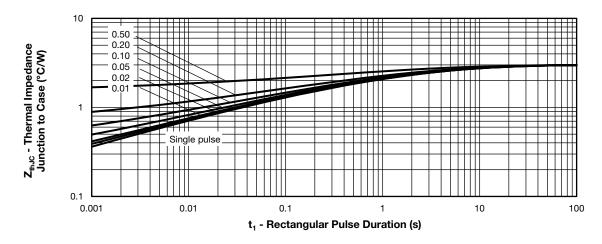


Fig. 4 - Max. Thermal Impedance Z<sub>thJC</sub> Characteristics

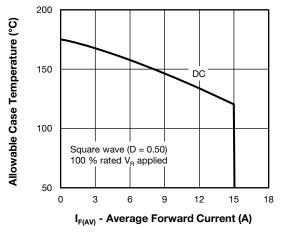


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

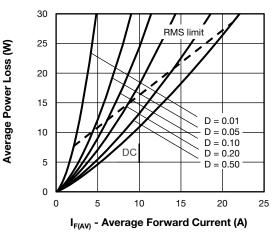


Fig. 6 - Forward Power Loss Characteristics

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### (E) 200 180 160 140 125 °C 140 125 °C 100 80 60 100 dl<sub>F</sub>/dt (A/µs)

Fig. 7 - Typical Reverse Recovery Time vs. dI<sub>F</sub>/dt

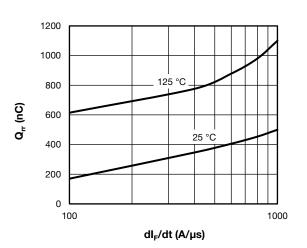


Fig. 8 - Typical Stored Charge vs. dl<sub>F</sub>/dt

### **ORDERING INFORMATION TABLE**

Device code	VS-	с	4	z	U	30	06	FP	-M3
	1	2	3	4	5	6	7	8	9
	1 -   2 -   3 -   4 -   5 -   6 -   7 -	Circ C = FRI Z = Pro U = Cur	EUIT CONF COMMO ED Pt G TO-3PF Cess typ ultrafas rent rati	packag	n: de ge ery = 2 x 15	A)			
	8 - 9 -	Env		ntal digit gen-free		-complia	ant, tern	nination	s lead (

ORDERING INFORMATION (Example)							
PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION							
VS-C4ZU3006FP-M3	25	300	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS						
Dimensions	TO-3PF	www.vishay.com/doc?96691				
Part marking information TO-3PF www.vishay.com/doc?96690						

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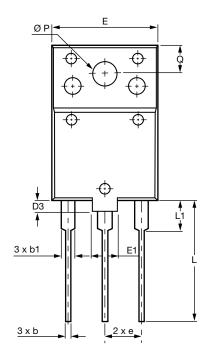


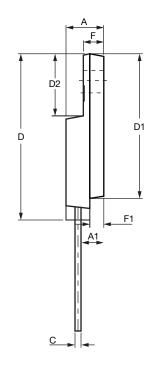


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TO-3PF

#### **DIMENSIONS** in millimeters





SYMBOL	MIN.	NOM.	MAX.				
A	5.30	5.50	5.70				
A1	3.10	3.30	3.50				
b	0.65	0.85	0.95				
b1	1.80	2.00	2.20				
с	0.80	0.90	1.10				
D	26.30	26.50	26.70				
D1	22.80	23.00	23.20				
D2	9.80	10.00	10.20				
D3	1.80	2.00	2.20				
E	15.30	15.50	15.70				
E1	3.80	4.00	4.20				
e		5.45 BSC					
F	2.80	3.00	3.20				
F1	1.80	2.00	2.20				
L	19.10	19.30	19.50				
L1	4.20	4.50	5.20				
Q	4.30	4.50	4.70				
ØP	3.40	3.60	3.80				

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